# **M74LS32P**

### **QUADRUPLE 2-INPUT POSITIVE OR GATES**

#### DESCRIPTION

The M74LS32P is a semiconductor integrated circuit containing 4 dual-input positive OR and negative AND gates.

#### **FEATURES**

- High breakdown input voltage (V₁ ≥ 15V)
- Low power dissipation (Pd = 20mW typical)
- High speed (tpd = 7ns typical)
- · Low output impedance
- Wide operating temperature range (T<sub>a</sub> = -20 ~ +75°C)

#### APPLICATION

General purpose, for use in industrial and consumer equipment.

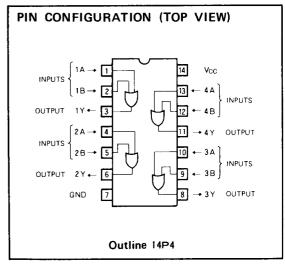
# FUNCTIONAL DESCRIPTION

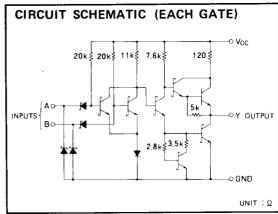
The use of Schottky TTL technology has enabled the achievement of input high breakdown voltage, high speed, low power dissipation, and high fan-out.

When either or both of the inputs A and B is/are high, output Y is high, and when both A and B are low, Y is low.

#### **FUNCTION TABLE**

Α	8	Υ
L	L	L
н	L	н
L	н	H
н	Н	н





#### ABSOLUTE MAXIMUM RATINGS ( $T_a = -20 \sim +75^{\circ}C$ , unless otherwise noted)

Symbol	Parameter	Conditions	Limits	Unit	
Vcc	Supply voltage		-0.5~+7	V	
VI	Input voltage		-0.5~+15	V	
Vo	Output voltage	High-level state	-0.5~ V <sub>CC</sub>	V	
Topr	Operating free-air ambient temperature range		<b>−20~+75</b>	ဗ	
Tstg	Storage temperature range		-65-+150	ొ	

### **QUADRUPLE 2-INPUT POSITIVE OR GATES**

### **RECOMMENDED OPERATING CONDITIONS** ( $T_a = -20 - +75$ °C, unless otherwise noted)

	_			Unit		
Symbol	Paramete	Parameter		Тур	Max	Ont
Vcc	Supply voltage		4.75	5	5.25	V
юн	High-level output current	V <sub>0H</sub> ≥2.7V	0		-400	μА
loL	Low-level output current $ V_{0L} \le 0.4V $ $V_{0L} \le 0.5V $	V <sub>OL</sub> ≦0.4V	0		4	mA
		0		8	mA	

#### ELECTRICAL CHARACTERISTICS (Ta = -20 ~ + 75°C, unless otherwise noted)

Symbol	Parameter			Limits			
		lest	Test conditions		Тур*	Max	Unit
VIH	High-level input voltage			2			٧
VIL	Low-level input voltage					0.8	V
VIC	Input clamp voltage	V <sub>CC</sub> =4.75V.1 <sub>IC</sub> =			-1.5	V	
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 4.75V$ , $V_{I} = 2V$ $I_{OH} = -400\mu A$		2.7	3.4		٧
		V <sub>CC</sub> = 4.75 V	I <sub>OL</sub> = 4mA		0.25	0.4	V
VoL	Low-level output voltage	V <sub>1</sub> =0.8V	I <sub>OL</sub> = 8mA		0.35	0.5	V
	I <sub>IH</sub> High-level input current	V <sub>CC</sub> =5.25V, V <sub>I</sub> =	2.7V			20	μА
ΉΗ		V <sub>CC</sub> =5.25V, V <sub>I</sub> =	V <sub>CC</sub> = 5 , 25V , V <sub>I</sub> = 10V			0.1	mA
I <sub>IL</sub>	Low-level input current	V <sub>CC</sub> =5.25V, V <sub>I</sub> =0.4V				-0.4	mA
los	Short-circuit output current (Note 1)	V <sub>CC</sub> = 5.25V, V <sub>O</sub> = 0V		- 20		- 100	mA
toch	Supply current, all outputs high	V <sub>CC</sub> =5.25V, V <sub>I</sub> =4.5V			3.1	6.2	mA
Iccl	Supply current, all outputs low	V <sub>CC</sub> =5.25V . V <sub>I</sub> =0V			4.9	9.8	mA

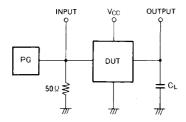
<sup>\* :</sup> All typical values are at  $V_{CC} = 5V$ ,  $Ta = 25^{\circ}C$ .

Note 1: All measurements should be done quickly, and not more than one output should be shorted at a time.

## SWITCHING CHARACTERISTICS (V<sub>CC</sub>=5V, Ta = 25°C, unless otherwise noted)

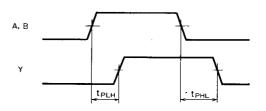
Symbol Parameter	Percenter	Test conditions	Limits			Unit
	raiantetei		Min	Тур	Max	Onit
telh	Low-to-high-level output propagation time	С <sub>L</sub> = 15 pF (Note 2)		7	22	ns
tphL	High-to-low-level output propagation time			7	22	ns

Note 2: Measurement circuit



- (1) The pulse generator (PG) has the following characteristics: PRR = 1MHz,  $t_r$  = 6ns,  $t_f$  = 6ns,  $t_w$  = 500ns,  $V_P$  = 3 $V_{P,P}$ ,  $Z_0$  = 50 $\Omega$
- (2) C<sub>L</sub> includes probe and jig capacitance.

## TIMING DIAGRAM (Reference level = 1.3V)



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